

## MBRB25H35CT, MBRB25H45CT, MBRB25H60CT

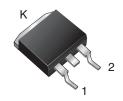
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Vishay General Semiconductor

## **Dual Common Cathode Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance

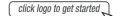
### D<sup>2</sup>PAK (TO-263AB)



#### MBRB25HxxCT



## **DESIGN SUPPORT TOOLS**





PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 15 A				
V <sub>RRM</sub>	35 V, 45 V, 60 V				
I <sub>FSM</sub>	150 A				
V <sub>F</sub>	0.54 V, 0.60 V				
I <sub>R</sub>	100 μΑ				
T <sub>J</sub> max.	175 °C				
Package	D <sup>2</sup> PAK (TO-263AB)				
Circuit configuration	Common cathode				

#### **FEATURES**

- Power pack
- · Guardring for overvoltage protection
- · Lower power losses, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

### **MECHANICAL DATA**

Case: D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

<b>MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBRB25H35CT	MBRB25H45CT	MBRB25H60CT	UNIT	
Maximum repetitive peak reverse voltage	$V_{RRM}$	35	45	60		
Working peak reverse voltage	$V_{RWM}$	35	45	60	V	
Maximum DC blocking voltage	$V_{DC}$	35	45	60		
May guarage forward restified guarant (fig. 1)		30				
Max. average forward rectified current (fig. 1) per diode	I <sub>F(AV)</sub>	15				
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 4$ A, L = 10 mH	E <sub>AS</sub>	80			mJ	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		150			Α	
Peak repetitive reverse surge current per diode at $t_p$ = 2.0 $\mu$ s, 1 kHz	I <sub>RRM</sub>	1.0	1.0	0.5	Α	
Peak non-repetitive reverse energy (8/20 µs waveform)	E <sub>RSM</sub>	25	25	20	mJ	
Electrostatic discharge capacitor voltage Human body model: C = 100 pF, R = 1.5 k $\Omega$	V <sub>C</sub>	25			kV	
Voltage rate of change (rated V <sub>R</sub> )		10 000			V/µs	
Operating junction and storage temperature range		-65 to +175			°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MBRB25H35CT MBRB25H45CT		MBRB25H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 15 A	T <sub>J</sub> = 25 °C	-	0.64	-	0.70	v
			T <sub>J</sub> = 125 °C	0.50	0.54	0.56	0.60	
		I <sub>F</sub> = 30 A	T <sub>J</sub> = 25 °C	-	0.74	ı	0.85	v
			I <sub>F</sub> = 30 A	I <sub>F</sub> = 30 A	T <sub>J</sub> = 125 °C	0.63	0.67	0.68
Maximum reverse current per diode	I <sub>R</sub> <sup>(2)</sup>	I <sub>R</sub> <sup>(2)</sup> Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	-	100	=	100	μA
			T <sub>J</sub> = 125 °C	6.0	20	4.0	20	mA

#### **Notes**

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBOL MBRB			
Thermal resistance, junction to case per diode	$R_{ heta JC}$	1.5	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	<b>DELIVERY MODE</b>	
TO-263AB	MBRB25H60CTHE3_A/P (1)	1.35	Р	50/tube	Tube	
TO-263AB	MBRB25H60CTHE3_A/I (1)	1.35	I	800/reel	Tape and reel	

### Note

(1) AEC-Q101 qualified

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## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>C</sub> = 25 °C unless otherwise noted)

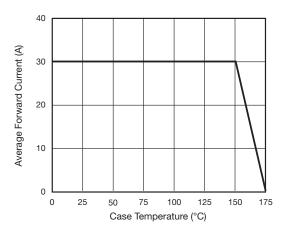


Fig. 1 - Forward Derating Curve (Total)

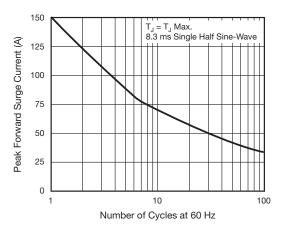


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

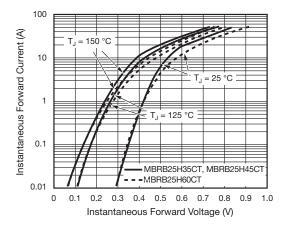


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

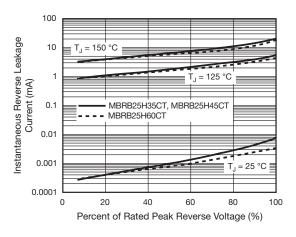


Fig. 4 - Typical Reverse Characteristics Per Diode

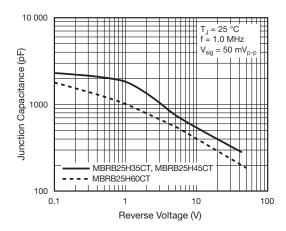


Fig. 5 - Typical Junction Capacitance Per Diode

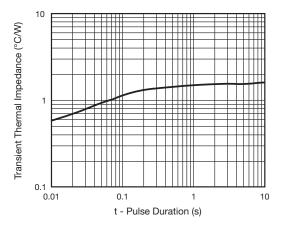


Fig. 6 - Typical Transient Thermal Impedance Per Diode



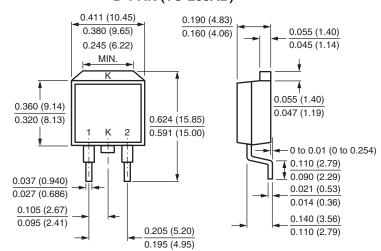
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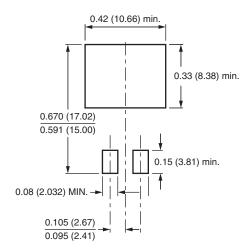
# PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

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## D<sup>2</sup>PAK (TO-263AB)



### **Mounting Pad Layout**





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